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MESFET Characteristics Formulas

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List of 13 MESFET Characteristics Formulas

MESFET Characteristics ↗

1) Cut-off Frequency ↗

fx

$$f_{co} = \frac{V_s}{4 \cdot \pi \cdot L_{gate}}$$

[Open Calculator ↗](#)

ex

$$30.05192\text{Hz} = \frac{5\text{mm/s}}{4 \cdot \pi \cdot 13.24\mu\text{m}}$$

2) Cut-off Frequency given Transconductance and Capacitance ↗

fx

$$f_{co} = \frac{g_m}{2 \cdot \pi \cdot C_{gs}}$$

[Open Calculator ↗](#)

ex

$$30.02923\text{Hz} = \frac{0.05\text{S}}{2 \cdot \pi \cdot 265\mu\text{F}}$$

3) Cut-off Frequency using Maximum Frequency ↗

fx

$$f_{co} = \frac{2 \cdot f_m}{\sqrt{\frac{R_d}{R_s + R_g + R_i}}}$$

[Open Calculator ↗](#)

ex

$$30.05347\text{Hz} = \frac{2 \cdot 65\text{Hz}}{\sqrt{\frac{450\Omega}{5.75\Omega + 2.8\Omega + 15.5\Omega}}}$$



4) Drain Resistance of MESFET

fx $R_d = \left(\frac{4 \cdot f_m^2}{f_{co}^2} \right) \cdot (R_s + R_g + R_i)$

[Open Calculator !\[\]\(cbe80b694ebd74fcfe136a095b608235_img.jpg\)](#)

ex $450.104\Omega = \left(\frac{4 \cdot (65\text{Hz})^2}{(30.05\text{Hz})^2} \right) \cdot (5.75\Omega + 2.8\Omega + 15.5\Omega)$

5) Gate Length of MESFET

fx $L_{gate} = \frac{V_s}{4 \cdot \pi \cdot f_{co}}$

[Open Calculator !\[\]\(3e2231b1ad3ca8da8658228c00dd08e0_img.jpg\)](#)

ex $13.24084\mu\text{m} = \frac{5\text{mm/s}}{4 \cdot \pi \cdot 30.05\text{Hz}}$

6) Gate Metallization Resistance

fx $R_g = \left(\frac{R_d \cdot f_{co}^2}{4 \cdot f_m^2} \right) - (R_s + R_i)$

[Open Calculator !\[\]\(0d5ec72f61334709c3fc9450209b754f_img.jpg\)](#)

ex $2.794445\Omega = \left(\frac{450\Omega \cdot (30.05\text{Hz})^2}{4 \cdot (65\text{Hz})^2} \right) - (5.75\Omega + 15.5\Omega)$



7) Gate Source Capacitance ↗

fx $C_{gs} = \frac{g_m}{2 \cdot \pi \cdot f_{co}}$

[Open Calculator ↗](#)

ex $264.8169\mu F = \frac{0.05S}{2 \cdot \pi \cdot 30.05Hz}$

8) Input Resistance ↗

fx $R_i = \left(\frac{R_d \cdot f_{co}^2}{4 \cdot f_m^2} \right) - (R_g + R_s)$

[Open Calculator ↗](#)

ex $15.49445\Omega = \left(\frac{450\Omega \cdot (30.05Hz)^2}{4 \cdot (65Hz)^2} \right) - (2.8\Omega + 5.75\Omega)$

9) Maximum Frequency of Oscillation given Transconductance ↗

fx $f_m = \frac{g_m}{\pi \cdot C_{gs}}$

[Open Calculator ↗](#)

ex $60.05847Hz = \frac{0.05S}{\pi \cdot 265\mu F}$



10) Maximum Frequency of Oscillations in MESFET ↗

fx $f_m = \left(\frac{f_t}{2} \right) \cdot \sqrt{\frac{R_d}{R_g}}$

[Open Calculator ↗](#)

ex $65.28817\text{Hz} = \left(\frac{10.3\text{Hz}}{2} \right) \cdot \sqrt{\frac{450\Omega}{2.8\Omega}}$

11) Source Resistance ↗

fx $R_s = \left(\frac{R_d \cdot f_{co}^2}{4 \cdot f_m^2} \right) - (R_g + R_i)$

[Open Calculator ↗](#)

ex $5.744445\Omega = \left(\frac{450\Omega \cdot (30.05\text{Hz})^2}{4 \cdot (65\text{Hz})^2} \right) - (2.8\Omega + 15.5\Omega)$

12) Transconductance in MESFET ↗

fx $g_m = 2 \cdot C_{gs} \cdot \pi \cdot f_{co}$

[Open Calculator ↗](#)

ex $0.050035\text{S} = 2 \cdot 265\mu\text{F} \cdot \pi \cdot 30.05\text{Hz}$



13) Transconductance in Saturation Region

[Open Calculator !\[\]\(eafc244b53721dd1ec133f0772f70fc7_img.jpg\)](#)

$$g_m = G_o \cdot \left(1 - \sqrt{\frac{V_i - V_g}{V_p}} \right)$$



$$0.050963S = 0.174S \cdot \left(1 - \sqrt{\frac{15.9V - 9.62V}{12.56V}} \right)$$



Variables Used

- C_{gs} Gate Source Capacitance (*Microfarad*)
- f_{co} Cut-off Frequency (*Hertz*)
- f_m Maximum Frequency of Oscillations (*Hertz*)
- f_t Unity Gain Frequency (*Hertz*)
- g_m Transconductance (*Siemens*)
- G_o Output Conductance (*Siemens*)
- L_{gate} Gate Length (*Micrometer*)
- R_d Drain Resistance (*Ohm*)
- R_g Gate Metallization Resistance (*Ohm*)
- R_i Input Resistance (*Ohm*)
- R_s Source Resistance (*Ohm*)
- V_g Gate Voltage (*Volt*)
- V_i Schottky Diode Potential Barrier (*Volt*)
- V_p Pinch Off Voltage (*Volt*)
- V_s Saturated Drift Velocity (*Millimeter per Second*)



Constants, Functions, Measurements used

- **Constant:** **pi**, 3.14159265358979323846264338327950288
Archimedes' constant
- **Function:** **sqrt**, sqrt(Number)
Square root function
- **Measurement:** **Length** in Micrometer (μm)
Length Unit Conversion ↗
- **Measurement:** **Speed** in Millimeter per Second (mm/s)
Speed Unit Conversion ↗
- **Measurement:** **Frequency** in Hertz (Hz)
Frequency Unit Conversion ↗
- **Measurement:** **Capacitance** in Microfarad (μF)
Capacitance Unit Conversion ↗
- **Measurement:** **Electric Resistance** in Ohm (Ω)
Electric Resistance Unit Conversion ↗
- **Measurement:** **Electric Conductance** in Siemens (S)
Electric Conductance Unit Conversion ↗
- **Measurement:** **Electric Potential** in Volt (V)
Electric Potential Unit Conversion ↗
- **Measurement:** **Transconductance** in Siemens (S)
Transconductance Unit Conversion ↗



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